SCLS261F - DECEMBER 1995 - REVISED JUNE 1996

- Operating Range 2-V to 5.5-V V<sub>CC</sub>
- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) Process
- High Latch-Up Immunity Exceeds 250 mA Per JEDEC Standard JESD-17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

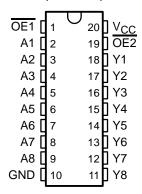
#### description

The 'AHC541 octal buffers/drivers are ideal for driving bus lines or buffer memory address registers. These devices feature inputs and outputs on opposite sides of the package to facilitate printed-circuit-board layout.

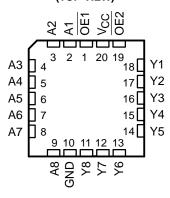
The 3-state control gate is a two-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all corresponding outputs are in the high-impedance state. The outputs provide noninverted data when they are not in the high-impedance state.

The SN54AHC541 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHC541 is characterized for operation from –40°C to 85°C.

#### SN54AHC541 . . . J OR W PACKAGE SN74AHC541 . . . DB, DW, N, OR PW PACKAGE (TOP VIEW)



## SN54AHC541 . . . FK PACKAGE (TOP VIEW)



## FUNCTION TABLE (each buffer/driver)

	INPUTS		OUTPUT
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	X	Χ	Z
Х	Н	Χ	Z

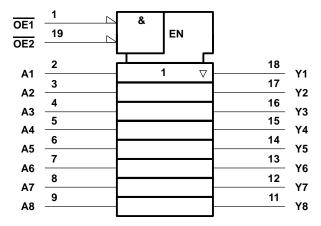


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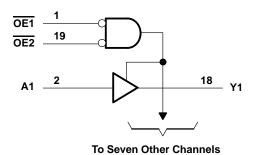


### logic symbol†



<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, $V_{CC}$ Input voltage range, $V_{I}$ (see Note 1)  Output voltage range, $V_{O}$ (see Note 1)  Input clamp current, $I_{IK}$ ( $V_{I}$ < 0 or $V_{I}$ > $V_{CC}$ )  Output clamp current, $I_{OK}$ ( $V_{O}$ < 0 or $V_{O}$ > $V_{CC}$ )  Continuous output current, $I_{O}$ ( $V_{O}$ = 0 to $V_{CC}$ )  Continuous current through $V_{CC}$ or GND  Maximum power dissipation at $T_{A}$ = 55°C (in still air) (see Note 2	): DB package	$\begin{array}{cccccccccccccccccccccccccccccccccccc$
•		1.6 W
	. •	1.3 W
	PW package	0.7 W
Storage temperature range, T <sub>stg</sub>		–65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>2.</sup> The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

### recommended operating conditions (see Note 3)

			SN54A	HC541	SN74A	HC541	UNIT	
			MIN	MAX	MIN	MAX	UNII	
Vcc	Supply voltage		2	5.5	2	5.5	V	
		V <sub>CC</sub> = 2 V	1.5		1.5			
ViH	High-level input voltage	V <sub>CC</sub> = 3 V	2.1		2.1		V	
		V <sub>CC</sub> = 5.5 V	3.85		3.85	2 5.5 1.5 2.1 .85 0.5 0.9 1.65 0 5.5 0 VCC -50 -4 -8 50 4 8 100 20		
		V <sub>CC</sub> = 2 V		0.5		0.5		
VIL	Low-level input voltage	V <sub>CC</sub> = 3 V		0.9		0.9	٧	
		V <sub>CC</sub> = 5.5 V		1.65		1.65		
VI	Input voltage		0	5.5	0	5.5	V	
٧o	Output voltage		0	VCC	0	VCC	V	
		V <sub>CC</sub> = 2 V		-50		-50	μΑ	
IOH	High-level output current	$V_{CC} = 3.3 \pm 0.3 \text{ V}$		-4		-4	mA	
		$V_{CC} = 5 \pm 0.5 \text{ V}$		-8		-8	IIIA	
		V <sub>CC</sub> = 2 V		50		50	μΑ	
loL	Low-level output current	$V_{CC} = 3.3 \pm 0.3 \text{ V}$		4		4	A	
		$V_{CC} = 5 \pm 0.5 \text{ V}$		8		8	mA	
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \pm 0.3 \text{ V}$		100		100	20/1	
ΔυΔν	Input transition rise or fall rate	$V_{CC} = 5 \pm 0.5 \text{ V}$		20		20	ns/V	
TA	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

D	ADAMETED	TEST CONDITIONS	\/	T,	Δ = 25°C	;	SN54A	HC541	SN74AI	HC541	LINIT	
F/	ARAWETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
			2 V	1.9	2		1.9		1.9			
		I <sub>OH</sub> = -50 μA	3 V	2.9	3		2.9		2.9			
PARAMETER  VOH  VOL  Data inputs Control inputs  IOZ <sup>†</sup> ICC C:		4.5 V	4.4	4.5		4.4		4.4		V		
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		2.48				
		$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8			
			2 V			0.1		0.1		0.1		
		Ι <sub>Ο</sub> L = 50 μΑ	3 V			0.1		0.1		0.1	V	
VOL	V <sub>OL</sub>		4.5 V			0.1		0.1		0.1		
VOL  II Data inputs Control inputs IOZ†	I <sub>OL</sub> = 4 mA	3 V			0.36		0.5		0.44			
		I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.5		0.44		
١.	Data inputs	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5 V			±0.1		±1		±1		
=	Control inputs	A = AGG OL GIND	3.5 V			±0.1		±1		±1	μΑ	
loz†		$V_O = V_{CC}$ or GND, $V_I (\overline{OE}) = V_{IL}$ or $V_{IH}$	5.5 V			±0.25		±2.5		±2.5	μΑ	
Icc	•	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ	
Ci		$V_I = V_{CC}$ or GND	5 V		2	10				10	pF	
Со		$V_O = V_{CC}$ or GND	5 V		4						pF	

<sup>†</sup> For input and ouput, IOZ includes the input leakage current.



### SN54AHC541, SN74AHC541 **OCTAL BUFFERS/DRIVERS** WITH 3-STATE OUTPUTS SCLS261F - DECEMBER 1995 - REVISED JUNE 1996

## switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

				SN	54AHC5	41			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C	;	MIN	MAX	UNIT	
	( 01)	(0011 01)	OAI AOITANOL	MIN TYP	MAX	IVIIIV	IVIAA		
tPLH*	А	Y	C <sub>L</sub> = 15 pF	5	7	1	8.5	ns	
<sup>t</sup> PHL*	A	ī	OL = 15 pr	5	7	1	8.5	115	
<sup>t</sup> PZH*	1	Ē Y		C: _ 15 pE	6	10.5	1	11	ns
tPZL*	OE		CL = 15 pr	6	10.5	1	11	115	
<sup>t</sup> PHZ*	ŌĒ	<b>~</b>	Y	7	11	1	12	ns	
tPLZ*		T T		7	11	1	12	115	
<sup>t</sup> PLH	Λ	V	Y C <sub>L</sub> = 50 pF	7.5	10.5	1	12	ns	
<sup>t</sup> PHL	Α	ĭ		7.5	10.5	1	12	115	
<sup>t</sup> PZH	ŌĒ	Y	C <sub>I</sub> = 50 pF	8	14	1	16	ns	
<sup>t</sup> PZL	OE	Y	C[ = 50 pr	8	14	1	16	115	
<sup>t</sup> PHZ	ŌĒ	V	Y	V 0: 50 = 5	9	15.4	1	17.5	ns
t <sub>PLZ</sub>	OE .	ľ	C <sub>L</sub> = 50 pF	9	15.4	1	17.5	115	

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

### switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

				SN	74AHC5	41		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C	;	MIN	MAX	UNIT
	( 01)	(0011 01)	OAI AGITAIVOE	MIN TYP	MAX	IVIIIN	WAA	
<sup>t</sup> PLH	А	Y	C <sub>I</sub> = 15 pF	5	7	1	8.5	ns
<sup>t</sup> PHL	^	I	OL = 13 pi	5	7	1	8.5	115
<sup>t</sup> PZH	<del>OE</del>	<b>&gt;</b>	Y C <sub>L</sub> = 15 pF	6	10.5	1	11	ns
<sup>t</sup> PZL	OE	'		6	10.5	1	11	115
<sup>t</sup> PHZ	ŌĒ	Y	C <sub>L</sub> = 15 pF	7	11	1	12	ns
<sup>t</sup> PLZ			OL = 15 pi	7	11	1	12	113
t <sub>PLH</sub>	Δ	V	C: F0.pF	7.5	10.5	1	12	
t <sub>PHL</sub>	Α	Y	C <sub>L</sub> = 50 pF	7.5	10.5	1	12	ns
<sup>t</sup> PZH	<u>OE</u>	Υ	C: F0.pF	8	14	1	16	
<sup>t</sup> PZL	OE	Ť	C <sub>L</sub> = 50 pF	8	14	1	16	ns
<sup>t</sup> PHZ	ŌĒ	Y	C: = 50 pE	9	15.4	1	17.5	ns
tPLZ	OE .	ľ	$C_L = 50 pF$	9	15.4	1	17.5	115

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

				SN	54AHC5	41			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C		MIN	MAX	UNIT	
	( 01)	(0011 01)	OAI AOITANOE	MIN TYP	MAX	IVIIIN	IVIAA		
tPLH*	А	Y	C <sub>L</sub> = 15 pF	3.5	5	1	6	ns	
<sup>t</sup> PHL*	٨	ı	OL = 13 pr	3.5	5	1	6	115	
<sup>t</sup> PZH*	ŌĒ	Y	C <sub>L</sub> = 15 pF	4.7	7.2	1	8.5	ns	
tPZL*		T	Γ	4.7	7.2	1	8.5	113	
<sup>t</sup> PHZ*	ŌĒ	OE	Y	C <sub>L</sub> = 15 pF	5	7.5	1	8	ns
tPLZ*		ī	- ΟΕ = 13 βι	5	7.5	1	8	115	
<sup>t</sup> PLH	Δ	V	Y C <sub>L</sub> = 50 pF	5	7	1	8	ns	
t <sub>PHL</sub>	Α	ī		5	7	1	8	110	
<sup>t</sup> PZH	<u>OE</u>	Y	C <sub>I</sub> = 50 pF	6.2	9.2	1	10.5	ns	
<sup>t</sup> PZL	OE	Y	C[ = 50 pr	6.2	9.2	1	10.5	110	
t <sub>PHZ</sub>	ŌĒ	Y	C <sub>L</sub> = 50 pF	6	8.8	1	10	ns	
tPLZ	) DE	ſ	OL = 50 pr	6	8.8	1	10	110	

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

					SN	74AHC5	41		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C			MIN	MAX	UNIT
	( 51)	(331.31)	674174611741612	MIN	TYP	MAX	IVIIIV	IVIAA	
t <sub>PLH</sub>	А	Y	C <sub>I</sub> = 15 pF		3.5	5	1	6	ns
t <sub>PHL</sub>		ı	OL = 13 pr		3.5	5	1	6	115
<sup>t</sup> PZH	ŌĒ	Y	C <sub>L</sub> = 15 pF		4.7	7.2	1	8.5	ns
t <sub>PZL</sub>	ÜE		OL = 13 βi		4.7	7.2	1	8.5	113
<sup>t</sup> PHZ	ŌĒ	Y	Y C <sub>L</sub> = 15 pF		5	7.5	1	8	ns
t <sub>PLZ</sub>	OL .		0[ – 10 рі		5	7.5	1	8	113
<sup>t</sup> PLH	А	Y	C: _ 50 pE		5	7	1	8	no
<sup>t</sup> PHL	A	ī	C <sub>L</sub> = 50 pF		5	7	1	8	ns
<sup>t</sup> PZH	ŌĒ	Y	C: _ 50 pF		6.2	9.2	1	10.5	no
tPZL	UE	Y	C <sub>L</sub> = 50 pF		6.2	9.2	1	10.5	ns
<sup>t</sup> PHZ	ŌĒ	Y	V 0 50-5		6	8.8	1	10	ns
t <sub>PLZ</sub>	OL	ī	C <sub>L</sub> = 50 pF		6	8.8	1	10	115

### output-skew characteristics, C<sub>L</sub> = 50 pF (see Note 4)

PARAMETER	5001			SN74A		
	FROM (INPUT)	TO (OUTPUT)	VCC	T <sub>A</sub> = 25°C	MIN MAX	UNIT
	(1141 01)	(0011 01)		MIN MAX		
•	۸	Y	$3.3~V \pm 0.3~V$	1.5	1.5	no
<sup>t</sup> sk(o)	А		5 V ± 0.5 V	1	1	ns

NOTE 4: Characteristics are determined during product characterization and ensured by design.



### noise characteristics, $V_{CC} = 5 \text{ V}$ , $C_L = 50 \text{ pF}$ , $T_A = 25^{\circ}\text{C}$ (see Note 5)

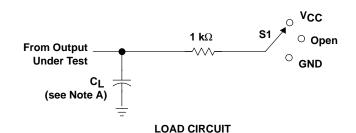
	PARAMETER	SN74AI	UNIT	
	PARAMETER	MIN 4.7	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.8	V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.8	V
VOH(V)	Quiet output, minimum dynamic VOH	4.7		V
VIH(D)	High-level dynamic input voltage	3.5		V
V <sub>IL(D)</sub>	Low-level dynamic input voltage		1.5	V

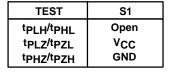
NOTE 5: Characteristics are determined during product characterization and ensured by design for surface-mount packages only.

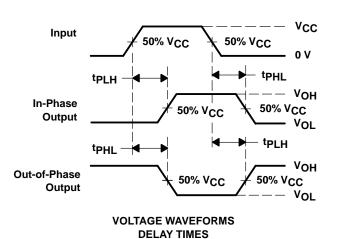
### operating characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

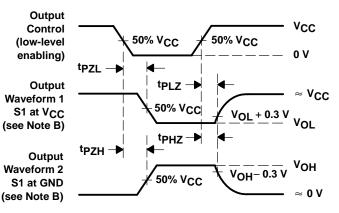
	PARAMETER  Cod Power dissipation capacitance		ONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	12	pF

#### PARAMETER MEASUREMENT INFORMATION









VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ ,  $t_f$  = 3 ns,  $t_f$  = 3 ns.
  - D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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